NSN 5962-01-366-0272

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Static operation
Inclosure Configuration:
Flat pack
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
11 input
Case Outline Source And Designator:
F-6 mil-m-38510
Product Name:
Microcircuit, digital, cmos, ram, static, 2048 x 8-bit
Voltage Rating And Type Per Characteristic:
-0.5 volts applied and 7.0 volts applied
Time Rating Per Chacteristic:
35.00 nanoseconds af output megawatts
Memory Device Type:
Ram
Hybrid Technology Type:
Monolithic
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
24 printed circuit
Specification Data:
81349-mil-m-38510 government specification
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
Yes - demil/mli
Fiig:
A458a0